## INTEGRATED CIRCUITS

## DATA SHEET

# **74ABT16841A**20-bit bus interface latch (3-State)

Product data 2004 Feb 02

Replaces data sheet 74ABT16841A/74ABTH16841A of 2002 Dec 17





## 20-bit bus interface latch (3-State)

## 74ABT16841A

#### **FEATURES**

- High speed parallel latches
- Live insertion/extraction permitted
- Extra data width for wide address/data paths or buses carrying parity
- Power-up 3-State
- Power-up reset
- Ideal where high speed, light loading, or increased fan-in are required with MOS microprocessors
- Output capability: +64 mA / -32 mA
- Latch-up protection exceeds 500 mA per Jedec Std 17
- ESD protection exceeds 2000 V per MIL STD 883 Method 3015 and 200 V per Machine Model

#### **DESCRIPTION**

The 74ABT16841A Bus interface latch is designed to provide extra data width for wider data/address paths of buses carrying parity.

The 74ABT16841A consists of two sets of ten D-type latches with 3-State outputs. The flip-flops appear transparent to the data when Latch Enable (nLE) is HIGH. This allows asynchronous operation, as the output transition follows the data in transition. On the nLE HIGH-to-LOW transition, the data that meets the set-up and hold time is latched.

Data appears on the bus when the Output Enable (n $\overline{\text{OE}}$ ) is LOW. When n $\overline{\text{OE}}$  is HIGH the output is in the high-impedance state.

#### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS T <sub>amb</sub> = 25 °C; GND = 0 V	TYPICAL	UNIT
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay nDx to nQx	$C_L = 50 \text{ pF}; V_{CC} = 5 \text{ V}$	3.1 2.2	ns
C <sub>IN</sub>	Input capacitance	$V_I = 0 \text{ V or } V_{CC}$	4	pF
C <sub>OUT</sub>	Output capacitance	$V_O = 0 \text{ V or } V_{CC}$ ; 3-State	7	pF
I <sub>CCZ</sub>	Outcoont outphy outront	Outputs disabled; V <sub>CC</sub> = 5.5 V	500	μΑ
I <sub>CCL</sub>	Quiescent supply current	Outputs LOW; $V_{CC} = 5.5 \text{ V}$	10	mA

#### ORDERING INFORMATION

 $T_{amb} = -40 \,^{\circ}C$  to  $+85 \,^{\circ}C$ 

Type number	Package	kage											
	Name	Description 1											
74ABT16841ADL	SSOP56	plastic shrink small outline package; 56 leads; body width 7.5 mm	SOT371-1										
74ABT16841ADGG	TSSOP56												

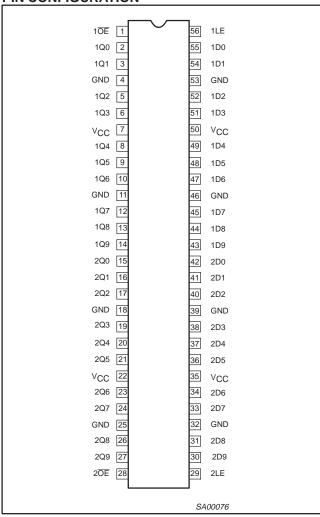
#### PIN DESCRIPTION

PIN NUMBER	SYMBOL	FUNCTION
55, 54, 52, 51, 49, 48, 47, 45, 44, 43 42, 41, 40, 38, 37, 36, 34, 33, 31, 30	1D0 – 1D9 2D0 – 2D9	Data inputs
2, 3, 5, 6, 8, 9, 10, 12, 13, 14 15, 16, 17, 19, 20, 21, 23, 24, 26, 27	1Q0 – 1Q9 2Q0 – 2Q9	Data outputs
1, 28	1 <del>OE</del> , 2 <del>OE</del>	Output enable inputs (active-LOW)
56, 29	1LE, 2LE	Latch enable inputs (active rising edge)
4, 11, 18, 25, 32, 39, 46, 53	GND	Ground (0 V)
7, 22, 35, 50	V <sub>CC</sub>	Positive supply voltage

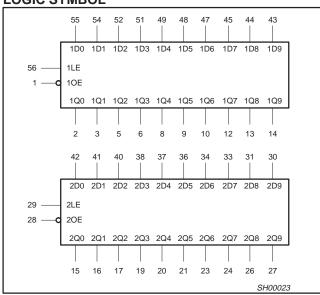
## 20-bit bus interface latch (3-State)

#### 74ABT16841A

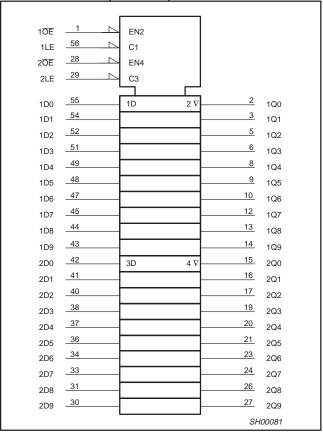




#### LOGIC SYMBOL



#### LOGIC SYMBOL (IEEE/IEC)



#### **FUNCTION TABLE**

	INPUTS	3	OUTPUTS	OPERATING MODE
nOE	nLE	nDx	nQ0 – nQ9	OPERATING MODE
L L	H	LΗ	L H	Transparent
L L	$\rightarrow$	l h	L H	Latched
Н	Х	Х	Z	High impedance
L	L	Х	NC	Hold

H = HIGH voltage level

h = HIGH voltage level one set-up time prior to the HIGH-to-LOW LE transition

L = LOW voltage level

= LOW voltage level one set-up time prior to the HIGH-to-LOW

LE transition

↓ = HIGH-to-LOW LE transition

NC= No change

X = Don't care

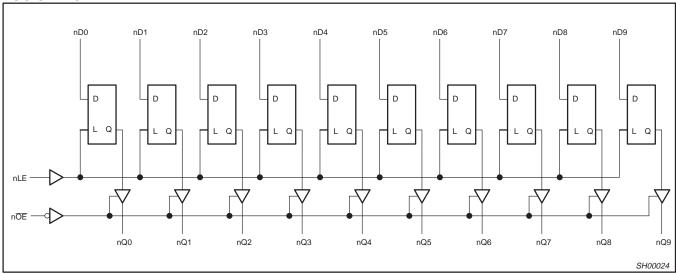
Z = High impedance "off" state

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## 20-bit bus interface latch (3-State)

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#### **LOGIC DIAGRAM**



#### **ABSOLUTE MAXIMUM RATINGS<sup>1, 2</sup>**

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT	
V <sub>CC</sub>	DC supply voltage		-0.5 to +7.0	V	
I <sub>IK</sub>	DC input diode current	V <sub>I</sub> < 0 V	-18	mA	
VI	DC input voltage <sup>3</sup>		−1.2 to +7.0	V	
I <sub>OK</sub>	DC output diode current	V <sub>O</sub> < 0 V	-50	mA	
V <sub>OUT</sub>	DC output voltage <sup>3</sup>	Output in Off or HIGH state	-0.5 to +5.5	V	
	DC submit surrest	Output in LOW state	128	A	
lout	DC output current	Output in HIGH state	-64	mA	
T <sub>stg</sub>	Storage temperature range		-65 to 150	°C	

#### NOTES:

- Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the
  device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to
  absolute-maximum-rated conditions for extended periods may affect device reliability.
- 2. The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150 °C.
- 3. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

#### **RECOMMENDED OPERATING CONDITIONS**

SYMBOL	PARAMETER	LIM	ITS	UNIT
STWIBOL	PARAMETER	Min	Max	UNIT
V <sub>CC</sub>	DC supply voltage	4.5	5.5	V
VI	Input voltage	0	V <sub>CC</sub>	V
V <sub>IH</sub>	HIGH-level input voltage	2.0	ı	V
V <sub>IL</sub>	LOW-level Input voltage	_	0.8	V
I <sub>OH</sub>	HIGH-level output current	-	-32	mA
I <sub>OL</sub>	LOW-level output current	_	64	mA
Δt/Δν	Input transition rise or fall rate	0	5	ns/V
T <sub>amb</sub>	Operating free-air temperature range	-40	+85	°C

## 20-bit bus interface latch (3-State)

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#### DC ELECTRICAL CHARACTERISTICS

					LIMITS	;		
SYMBOL	PARAMETER	TEST CONDITIONS	T <sub>an</sub>	<sub>nb</sub> = +25	°C	T <sub>amb</sub> = to +8	–40 °C 35 °C	UNIT
			Min	Тур	Max	Min	Max	
V <sub>IK</sub>	Input clamp voltage	$V_{CC} = 4.5 \text{ V}; I_{IK} = -18 \text{ mA}$	_	-0.9	-1.2	-	-1.2	V
		$V_{CC} = 4.5 \text{ V}; I_{OH} = -3 \text{ mA}; V_I = V_{IL} \text{ or } V_{IH}$	2.5	2.9	-	2.5	-	V
V <sub>OH</sub>	HIGH-level output voltage	$V_{CC} = 5.0 \text{ V}; I_{OH} = -3 \text{ mA}; V_I = V_{IL} \text{ or } V_{IH}$	3.0	3.4	-	3.0	-	V
		$V_{CC} = 4.5 \text{ V}; I_{OH} = -32 \text{ mA}; V_I = V_{IL} \text{ or } V_{IH}$	2.0	2.4	_	2.0	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_{CC} = 4.5 \text{ V}; I_{OL} = 64 \text{ mA}; V_I = V_{IL} \text{ or } V_{IH}$	_	0.42	0.55	-	0.55	V
V <sub>RST</sub>	Power-up output voltage <sup>3</sup>	$V_{CC} = 5.5 \text{ V}$ ; $I_O = 1 \text{ mA}$ ; $V_I = \text{GND or } V_{CC}$	_	0.13	0.55	-	0.55	V
I <sub>I</sub>	Input leakage current	$V_{CC} = 5.5 \text{ V}; V_I = V_{CC} \text{ or GND}$	_	±0.01	±1	_	±1.0	μА
I <sub>OFF</sub>	Power-off leakage current	$V_{CC} = 0.0 \text{ V}; V_{O} \text{ or } V_{I} \le 4.5 \text{ V}$	_	±5.0	±100	_	±100	μΑ
I <sub>PU/PD</sub>	Power-up/down 3-State output current <sup>4</sup>	$V_{CC}$ = 2.1 V; $V_O$ = 0.5 V; $V_I$ = GND or $V_{CC}$ ; $V_{OE}$ = Don't care	_	±5.0	±50	_	±50	μА
I <sub>OZH</sub>	3-State output High current	$V_{CC} = 5.5 \text{ V}; V_{O} = 2.7 \text{ V}; V_{I} = V_{IL} \text{ or } V_{IH}$	_	5.0	10	_	10	μΑ
I <sub>OZL</sub>	3-State output Low current	$V_{CC} = 5.5 \text{ V}; V_{O} = 0.5 \text{ V}; V_{I} = V_{IL} \text{ or } V_{IH}$	_	-5.0	-10	-	-10	μΑ
I <sub>CEX</sub>	Output High leakage current	$V_{CC} = 5.5 \text{ V}; V_{O} = 5.5 \text{ V}; V_{I} = \text{GND or } V_{CC}$	_	5.0	50	-	50	μΑ
I <sub>O</sub>	Output current <sup>1</sup>	$V_{CC} = 5.5 \text{ V}; V_{O} = 2.5 \text{ V}$	-50	-70	-180	-50	-180	mA
I <sub>CCH</sub>		$V_{CC} = 5.5 \text{ V}$ ; Outputs High, $V_{I} = \text{GND or } V_{CC}$	_	0.5	1	-	1	mA
I <sub>CCL</sub>	Quiescent supply current	$V_{CC}$ = 5.5 V; Outputs Low, $V_I$ = GND or $V_{CC}$	_	10	19	-	19	mA
I <sub>CCZ</sub>		$V_{CC} = 5.5 \text{ V}$ ; Outputs 3-State; $V_I = \text{GND or } V_{CC}$	_	0.5	1	-	1	mA
ΔI <sub>CC</sub>	Additional supply current per input pin <sup>2</sup>	$V_{CC}$ = 5.5 V; one input at 3.4 V, other inputs at $V_{CC}$ or GND	_	0.2	1	_	1	mA

#### NOTES:

- 1. Not more than one output should be tested at a time, and the duration of the test should not exceed one second.
- This is the increase in supply current for each input at 3.4 V.
   For valid test results, data must not be loaded into the flip-flops (or latches) after applying the power.
- This parameter is valid for any V<sub>CC</sub> between 0 V and 2.1 V with a transition time of up to 10 msec. From V<sub>CC</sub> = 2.1 V to V<sub>CC</sub> = 5 V ± 10% a transition time of up to 100 μsec is permitted.
   Unused pins at V<sub>CC</sub> or GND.

AC CHARACTERISTICS GND = 0 V,  $t_R$  =  $t_F$  = 2.5 ns,  $C_L$  = 50 pF,  $R_L$  = 500  $\Omega$ 

SYMBOL	PARAMETER	WAVEFORM	T,	<sub>amb</sub> = +25 / <sub>CC</sub> = +5.0	°C V	T <sub>amb</sub> = -40 V <sub>CC</sub> = +5.	UNIT		
			MIN	TYP	MAX	MIN	MAX		
t <sub>PLH</sub>	Propagation delay nDx to nQx	2	1.1 1.5	3.1 2.2	4.1 3.1	1.1 1.5	4.9 3.6	ns	
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay nLE to nQx	1	1.5 1.0	2.5 2.1	3.3 2.8	1.5 1.0	3.7 3.1	ns	
t <sub>PZH</sub> t <sub>PZL</sub>	Output enable time to HIGH and LOW level	4 5	1.2 1.2	2.4 2.2	3.2 2.9	1.2 1.2	4.0 3.6	ns	
t <sub>PHZ</sub> t <sub>PLZ</sub>	Output disable time from HIGH and LOW level	4 5	1.8 1.5	3.0 2.5	4.0 3.2	1.8 1.5	4.9 3.7	ns	

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## 20-bit bus interface latch (3-State)

## 74ABT16841A

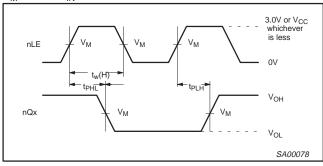
#### **AC SET-UP REQUIREMENTS**

GND = 0 V,  $t_R$  =  $t_F$  = 2.5 ns,  $C_L$  = 50 pF,  $R_L$  = 500  $\Omega$ 

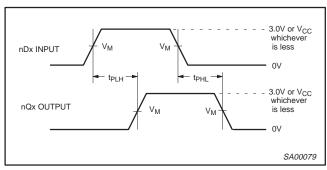
SYMBOL	PARAMETER	WAVEFORM	T <sub>amb</sub> = V <sub>CC</sub> =	+25 °C +5.0 V	T <sub>amb</sub> = -40 V <sub>CC</sub> = +5.	UNIT	
			Min	Тур	Min	Max	
$t_{s}(H)$ $t_{s}(L)$	Set-up time, HIGH or LOW nDx to nLE	3	2.0 1.0	1.0 0.4	2.0 1.0	-	ns
t <sub>h</sub> (H) t <sub>h</sub> (L)	Hold time, HIGH or LOW nDx to nLE	3	2.0 2.0	-0.3 -0.7	2.0 2.0	-	ns
t <sub>w</sub> (H)	nLE pulse width HIGH	1	2.9	1.9	2.9	_	ns

#### **AC WAVEFORMS**

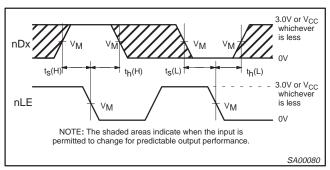
 $V_M = 1.5 \text{ V}, V_{IN} = \text{GND to } 3.0 \text{ V}$ 



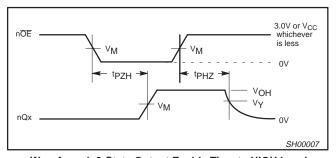
Waveform 1. Propagation Delay, Latch Enable Input to Output, and Enable Pulse Width



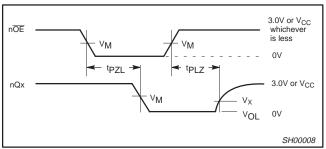
Waveform 2. Propagation Delay for Data to Outputs



Waveform 3. Data Set-up and Hold Times



Waveform 4. 3-State Output Enable Time to HIGH Level and Output Disable Time from HIGH Level

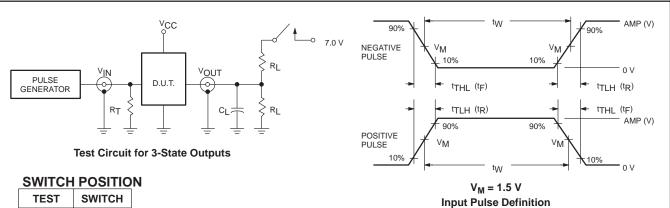


Waveform 5. 3-State Output Enable Time to LOW Level and Output Disable Time from LOW Level

## 20-bit bus interface latch (3-State)

## 74ABT16841A

#### **TEST CIRCUIT AND WAVEFORM**



TEST	SWITCH
t <sub>PLZ</sub>	closed
t <sub>PZL</sub>	closed
All other	open

#### **DEFINITIONS**

 $R_L$  = Load resistor; see AC CHARACTERISTICS for value.

 $C_L = Load$  capacitance includes jig and probe capacitance; see AC CHARACTERISTICS for value.

 $R_T = Termination resistance should be equal to <math>Z_{OUT}$  of pulse generators.

FAMILY	IN	INPUT PULSE REQUIREMENTS									
	Amplitude	Rep. Rate	t <sub>W</sub>	t <sub>R</sub>	t <sub>F</sub>						
74ABT	3.0 V	1 MHz	500 ns	2.5 ns	2.5 ns						

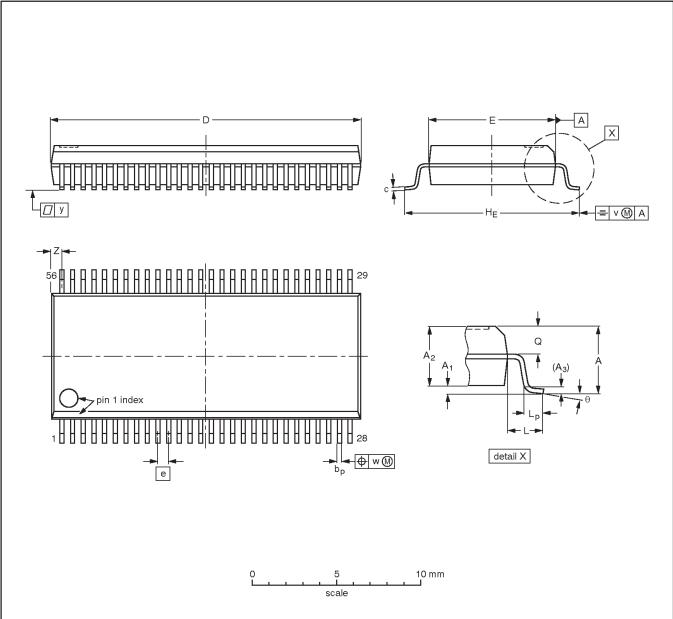
SA00654

## 20-bit bus interface latch (3-State)

## 74ABT16841A

#### SSOP56: plastic shrink small outline package; 56 leads; body width 7.5 mm

SOT371-1



#### **DIMENSIONS (mm are the original dimensions)**

UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	A <sub>3</sub>	b <sub>p</sub>	С	D <sup>(1)</sup>	E <sup>(1)</sup>	е	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
mm	2.8	0.4 0.2	2.35 2.20	0.25	0.3 0.2	0.22 0.13	18.55 18.30	7.6 7.4	0.635	10.4 10.1	1.4	1.0 0.6	1.2 1.0	0.25	0.18	0.1	0.85 0.40	8° 0°

#### Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFEF	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT371-1		MO-118				<del>99-12-27</del> 03-02-18	

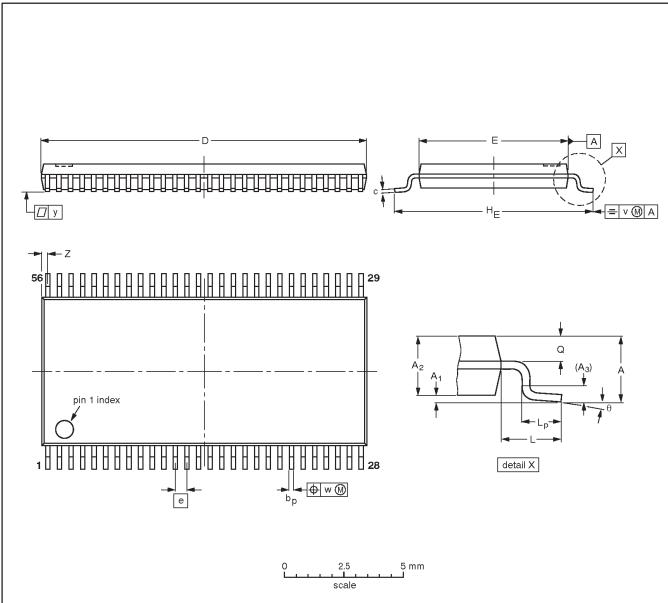
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## 20-bit bus interface latch (3-State)

## 74ABT16841A

#### TSSOP56: plastic thin shrink small outline package; 56 leads; body width 6.1 mm

SOT364-1



#### DIMENSIONS (mm are the original dimensions).

UNIT	A max.	Α1	A <sub>2</sub>	А3	bp	c	D <sup>(1)</sup>	E <sup>(2)</sup>	е	HE	L	Lp	Q	٧	w	у	z	θ
mm	1.2	0.15 0.05	1.05 0.85	0.25	0.28 0.17	0.2 0.1	14.1 13.9	6.2 6.0	0.5	8.3 7.9	1	0.8 0.4	0.50 0.35	0.25	0.08	0.1	0.5 0.1	8° 0°

#### Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ICCUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT364-1		MO-153				<del>-99-12-27-</del> 03-02-19	

## 20-bit bus interface latch (3-State)

## 74ABT16841A

#### **REVISION HISTORY**

Rev	Date	Description	
_3	20040202	Product data (9397 750 12821); 853-1797 ECN 01–A15433 of 27 January 2004. Replaces data sheet 74ABT_H16841A_2 of 2002 Dec 17 (9397 750 10845). Modifications:	
		Modifications:	
		Delete all references to 74ABTH16841A (product discontinued).	
_2	20021217	Product data (9397 750 10845); ECN 853-1797 29296 of 12 December 2002. Supersedes data of 27 February 1998 (9397 750 03506).	
_1	19980227	Product specification (9397 750 03506). ECN 853-1797 19025 of 27 February 1998.	

## 20-bit bus interface latch (3-State)

74ABT16841A

#### Data sheet status

Level	Data sheet status <sup>[1]</sup>	Product status <sup>[2]</sup> [3]	Definitions
I	Objective data	Development	This data sheet contains data from the objective specification for product development.  Philips Semiconductors reserves the right to change the specification in any manner without notice.
II	Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
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<sup>[1]</sup> Please consult the most recently issued data sheet before initiating or completing a design.

#### **Definitions**

**Short-form specification** — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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<sup>[2]</sup> The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.

<sup>[3]</sup> For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.